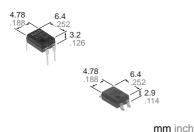


GU (General Use)-E Type 1-Channel (Form B) 4-pin Type

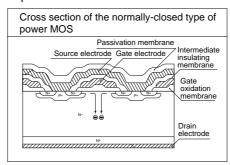


FEATURES

1. Low on resistance for normallyclosed type

This has been realized thanks to the builtin MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.

Cross section of the normally-closed type of power MOS



2. Reinforced insulation 5,000 V type More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

3. Compact 4-pin DIP size

The device comes in a compact (W)6.4×(L)4.78×(H)3.2mm (W).252×(L).188×(H).126inch, 4-pin DIP size

PhotoMOS RELAYS

4. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

5. High sensitivity, low ON resistance

Can control a maximum 0.13 A load current with a 5 mA input current. Low ON resistance of 18Ω (AQY410EH). Stable operation because there are no metallic contact parts.

6. Low-level off state leakage current

TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Security equipment
- Sensors

TYPES

	I/O isolation voltage	Output rating*			Pa	Packing quantity			
Туре				Through hole terminal	Surface-mount terminal				
		Lood	and land	Tube packing style		Tape and reel packing style			Tana and
		Load Load voltage curren	current			Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	Tape and reel
AC/DC	Reinforced 5,000 V	350 V	130 mA	AQY410EH	AQY410EHA	AQY410EHAX	AQY410EHAZ	1 tube contains 100 pcs.	1,000 pcs.
type		400 V	120 mA	AQY414EH	AQY414EHA	AQY414EHAX	AQY414EHAZ	1 batch contains 1,000 pcs.	

*Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the product number "AQY", the SMD terminal shape indicator "A" and the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY410EH (A) AQY414EH (A)		Remarks	
	LED forward current	lF	50 m			
Input	LED reverse voltage	Vr	3 \			
	Peak forward current	FP	1 A	f = 100 Hz, Duty factor = 0.1%		
	Power dissipation	Pin	75 m			
Output	Load voltage (peak AC)	VL	350 V	400 V		
	Continuous load current	١L	0.13 A	0.12 A		
	Peak load current	Ipeak	0.4 A	0.3 A	100 ms (1 shot), VL= DC	
	Power dissipation	Pout	500 mW			
Total power dissipation		P⊤	550 mW			
I/O isolation voltage		Viso	5,000 \			
Tempe	erature Operating	Topr	−40°C to +85°C −40°F to +185°F		Non-condensing at low temperatures	
lin	nits Storage	Tstg	-40°C to +100°C -			

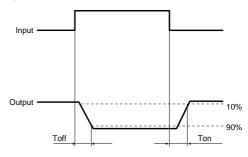
AQY41OEH

	Item		Symbol	AQY410EH (A)	AQY414EH (A)	Condition	
	LED operate	Typical		1.4 mA	1.3 mA	L Mau	
	(OFF) current	Maximum	Foff	3.0 mA		I∟=Max.	
loout	LED reverse (ON) current	Minimum	Fon	0.4	L-Mox		
Input		Typical	IFon	1.3 mA	1.2 mA	I∟=Max.	
	LED dropout voltage	Typical	VF	1.14 (1.25 V a	I⊧ = 5 mA		
		Maximum	VF	1.5			
	On resistance	Typical	Ron	18Ω	26Ω	I⊧ = 0 mA I∟ = Max. Within 1 s on time	
Output		Maximum		25Ω	35Ω		
·	Off state leak- age current	Maximum	ILeak	10µA		l⊧ = 5 mA V∟ = Max.	
	Operate (OFF) time*	Typical	Toff	1.0 ms	0.8 ms	I⊧ = 0 mA>5 mA	
		Maximum	loff	3.0 ms		l∟ = Max.	
	Reverse (ON) time*	Typical	Ton	0.3 ms	0.2 ms	l⊧ = 5 mA>0 mA	
ansfer char-		Maximum	Ion	1.0 ms		I∟ = Max.	
acteristics	I/O capacitance	Typical	Ciso	0.8 pF		f =1MHz Vв =0	
		Maximum	CISO	1.5			
	Initial I/O isola- tion resistance	Minimum	Riso	1,000ΜΩ		500 V DC	

Note: Recommendable LED forward current $I_F = 5$ to 10mA.



For type of connection



■ For Dimensions, see Page 440.

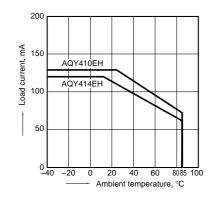
■ For Schematic and Wiring Diagrams, see Page 445.

■ For Cautions for Use, see Page 449.

REFERENCE DATA

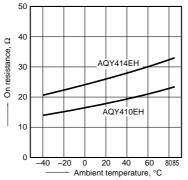
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



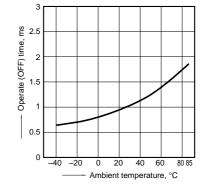
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 0 mA; Load voltage: Max.(DC); Continuous load current: Max. (DC)



3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



AQY41OEH

6. LED reverse (ON) current vs. ambient tem-

perature characteristics

-40 -20 0 20 40 60 8085

Continuous load current: Max. (DC)

Load voltage: Max. (DC);

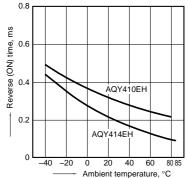
5 ۳

current,

LED reverse (ON) off

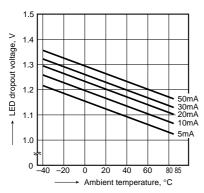
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



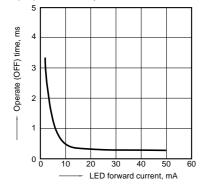
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



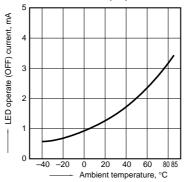
10. LED forward current vs. Operate (OFF) time characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



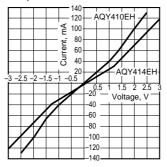
5. LED operate (OFF) current vs. ambient temperature characteristics Load voltage: Max. (DC);

Continuous load current: Max. (DC)



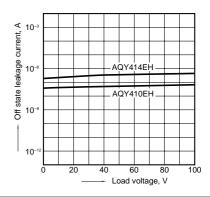
8. Voltage vs. current characteristics of out-put at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



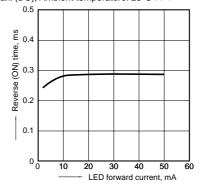
9. Off state leakage current Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F

Ambient temperature, °C



11. LED forward current vs. Reverse (ON) time characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: $25^{\circ}C$ $77^{\circ}F$

